

Green Products

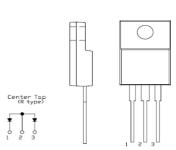
MBRF40200CTR SCHOTTKY RECTIFIER

Applications:

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

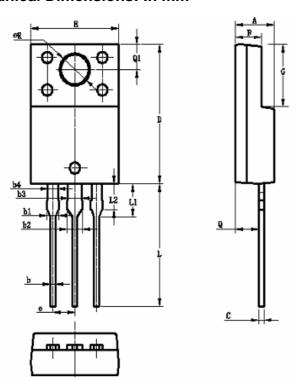
Features:

- 150 ℃ T J operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request



OUTLINE DRAWING

Mechanical Dimensions: In mm



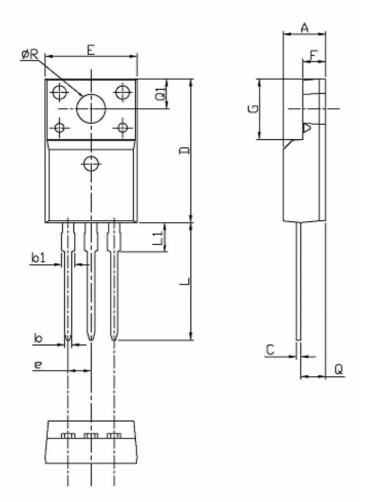
	OPTION 1(CJ)		OPTION	OPTION 2(HD)	
Dim	Min	Max	Min	Max	
Α	4.4	4.6	4.30	4.70	
b	0.6T	ΥP	0.50	0.75	
b1	1.3T	ΥP	1.30	1.40	
b2	1.7T	ΥP	1.70	1.80	
b3	1.6T	ΥP	1.50	1.75	
b4	1.2T	ΥP	1.10	1.35	
С	0.60	ГҮР	0.50	0.75	
D	14.8	15.1	14.80	15.20	
Е	10.06	10.26	9.96	10.36	
е	2.55TYP		2.54TYP		
F	2.9 3.1		2.80	3.20	
G	6.5	6.9	6.50	6.90	
L	12.7	13.7	12.8	13.2	
L1	3.4	3.8	3.60	4.00	
L2	2.6	3.0	-	-	
Q	2.5	2.9	2.50	2.90	
Q1	2.5 2.9		2.70REF		
ØR	3.5REF		3.50	3.50REF	

[•] Weiqi Street, Airport Development Zone, Jiangning District, Nanjing, China 211113 🗏 (86) 25-87123907 •

[•] FAX (86) 25-87123900 • World Wide Web Site - http://www.sangdest.com.cn • E-Mail Address - sales@ sangdest.com.cn •



Green Products

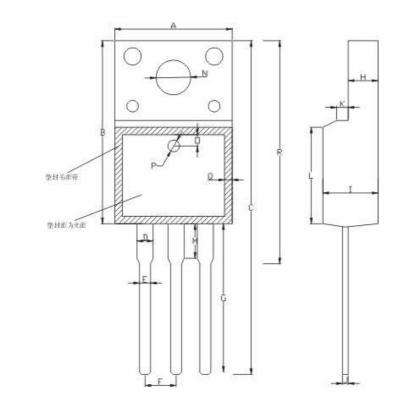


	OPTION 3		OPTION 4	
Dim	Min	Max	Min	Max
Α	4.53	4.93	4.50	4.90
b	0.71	0.91	0.70	0.90
b1	1.15	1.39	1.33	1.47
С	0.36	0.53	0.45	0.60
D	15.67	16.07	15.67	16.07
E	9.96	10.36	9.96	10.36
е	2.54	ГҮР	2.54 BSC	
F	2.34	2.76	2.34	2.74
G	6.50	6.90	6.48	6.88
L	12.37	12.77	12.78	13.18
L1	2.23	2.63	3.03	3.43
Q	2.56	2.96	2.56	2.96
Q1	3.10	3.50	3.10	3.50
ØR	2.98	3.38	3.08	3.28

[•] Weiqi Street, Airport Development Zone, Jiangning District, Nanjing, China 211113 🗏 (86) 25-87123907 •

[•] FAX (86) 25-87123900 • World Wide Web Site - http://www.sangdest.com.cn • E-Mail Address - sales@ sangdest.com.cn •

Green Products



A:10.20	± 0.50	B:15.90	± 0.50	C:29.00	± 1.00	D:1.24	±0.10
E:0.80	± 0.10	F:2.54	± 0.10	G:13.10	$\pm 1,0$	H:2.55	± 0.05
I:4.70	±0.05	J:0.50	± 0.05	K:1.20	±0.20	L:8.00	± 0.50
M:3.00	± 0.50	N:3.20	± 0.20	O:1,25	±0.05	P:1.5	± 0.05
Q:1.0	±0.20	R:19.2	±1.0				

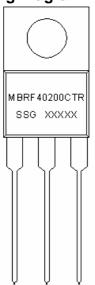
OPTION 5 (SR)

ITO-220AB



Green Products

Marking Diagram:



Where XXXXX is YYWWL

MBR = Device Type F = Package type

40 = Forward Current (40A) 200 = Reverse Voltage (200V)

CTR = Configuration

SSG = SSG YY = Year WW = Week L = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

Ordering Information:

Device	Package	Shipping
MBRF40200CTR	ITO-220AB	50pcs / tube
MBRF40200CTR	(Pb-Free)	50pcs / tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V_{RWM}	-	200	V
Max. Average Forward Current	I _{F(AV)}	50% duty cycle @T _C =105℃, rectangular wave form	40	А
Max. Peak One Cycle Non- Repetitive Surge Current (per leg)	I _{FSM}	8.3 ms, half Sine pulse	396	Α

[•] Weiqi Street, Airport Development Zone, Jiangning District, Nanjing, China 211113 🗏 (86) 25-87123907 •

[•] FAX (86) 25-87123900 • World Wide Web Site - http://www.sangdest.com.cn • E-Mail Address - sales@ sangdest.com.cn •

Green Products

Electrical Characteristics:

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop (per leg)*	V_{F1}	@ 20A, Pulse, T _J = 25 °C	0.95	V
	V_{F2}	@ 20A, Pulse, T _J = 125 °C	0.85	V
Max. Reverse Current (per leg)*	I _{R1}	$@V_R = \text{rated } V_R$ $T_J = 25 ^{\circ}\text{C}$	1.0	mA
	I _{R2}	$@V_R = \text{rated } V_R$ $T_J = 125 ^{\circ}\text{C}$	11	mA
Max. Junction Capacitance (per leg)	Ст	$@V_R = 5V, T_C = 25 ^{\circ}C$ $f_{SIG} = 1MHz$	450	pF
Typical Series Inductance (per leg)	L _s	Measured lead to lead 5 mm from package body	8.0	nH
Max. Voltage Rate of Change	dv/dt	-	10,000	V/μs
RSM Isolation Voltage (t = 1.0 second, R. H. < =30%, $T_A = 25$ °C)	V	Clip mounting, the epoxy body away from the heatsink edge by more than 0.110" along the lead direction.	4500	V
	V _{ISO}	Clip mounting, the epoxy body is inside the heatsink.	3500	V
		Screw mounting, the epoxy body is inside the heatsink.	1500	

^{*} Pulse Width < $300\mu s$, Duty Cycle <2%

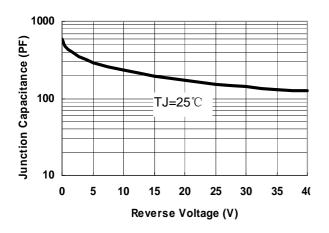
Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Max. Junction Temperature	T_J	-	-55 to +150	°C
Max. Storage Temperature	T _{stg}	-	-55 to +150	°C
Maximum Thermal Resistance Junction to Case (per leg)	$R_{ heta JC}$	DC operation	2.0	°C/W
Approximate Weight	wt	-	2	g
Case Style		ITO-220AB		•

[•] Weiqi Street, Airport Development Zone, Jiangning District, Nanjing, China 211113 🗏 (86) 25-87123907 •

[•] FAX (86) 25-87123900 • World Wide Web Site - http://www.sangdest.com.cn • E-Mail Address - sales@ sangdest.com.cn •

Green Products



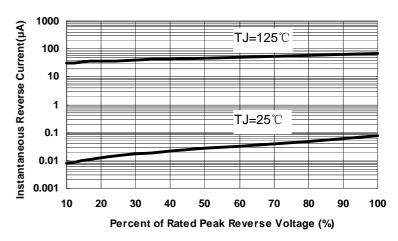


Fig.1-Typical Junction Capacitance

Fig.2-Typical Reverse Characteristics

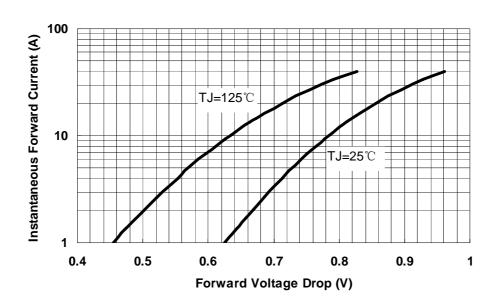


Fig.3-Typical Instantaneous Forward Voltage Characteristics

[•] Weiqi Street, Airport Development Zone, Jiangning District, Nanjing, China 211113 🗏 (86) 25-87123907 •

[•] FAX (86) 25-87123900 • World Wide Web Site - http://www.sangdest.com.cn • E-Mail Address - sales@ sangdest.com.cn •



MBRF40200CTR

Technical Data Data Sheet N0859, Rev. A **Green Products**

DISCLAIMER:

- 1- The information given herein, including the specifications and dimensions, is subject to change without prior notice to improve product characteristics. Before ordering, purchasers are advised to contact the SMC Sangdest Microelectronics (Nanjing) Co., Ltd sales department for the latest version of the datasheet(s).
- 2- In cases where extremely high reliability is required (such as use in nuclear power control, aerospace and aviation, traffic equipment, medical equipment, and safety equipment), safety should be ensured by using semiconductor devices that feature assured safety or by means of users' fail-safe precautions or other arrangement.
- 3- In no event shall SMC Sangdest Microelectronics (Nanjing) Co., Ltd be liable for any damages that may result from an accident or any other cause during operation of the user's units according to the datasheet(s). SMC Sangdest Microelectronics (Nanjing) Co., Ltd assumes no responsibility for any intellectual property claims or any other problems that may result from applications of information, products or circuits described in the datasheets.
- 4- In no event shall SMC Sangdest Microelectronics (Nanjing) Co., Ltd be liable for any failure in a semiconductor device or any secondary damage resulting from use at a value exceeding the absolute maximum rating.
- 5- No license is granted by the datasheet(s) under any patents or other rights of any third party or SMC Sangdest Microelectronics (Nanjing) Co., Ltd.
- 6- The datasheet(s) may not be reproduced or duplicated, in any form, in whole or part, without the expressed written permission of SMC Sangdest Microelectronics (Nanjing) Co., Ltd.
- 7- The products (technologies) described in the datasheet(s) are not to be provided to any party whose purpose in their application will hinder maintenance of international peace and safety nor are they to be applied to that purpose by their direct purchasers or any third party. When exporting these products (technologies), the necessary procedures are to be taken in accordance with related laws and regulations...